AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A light emitting device comprising:

a light ~~emitting~~ emitting chip; and

a phosphor through which a first light emitting from the light emitting chip passes,

wherein the phosphor comprises a silicate phosphor exciting a second light having a first centered emission peak using the first light and a sulfide phosphor exciting a third light having a second centered emission peak using the first light, and

wherein the silicate phosphor has a chemical formula of $Sr_{3-x}SiO_5:Eu^{2+}_x(0 < x \leq 1)$, and wherein the sulfide phosphor has a chemical formula of $Sr_{1-x}Ga_2S_4:Eu^{2+}_x(0.001 \leq x \leq 1)$.

2. (Original) The light emitting device according to claim 1, wherein the first centered emission peak is in a range of 550 - 600 nm.

3. (Original) The light emitting device according to claim 1, wherein the second centered emission peak is in a range of 500 - 550 nm.

4-5. (Cancelled)

6. (Original) The light emitting device according to claim 1, wherein the silicate phosphor and the sulfide phosphor exist at a ratio of 1 : 1 to 1 : 9.

7. (Original) The light emitting device according to claim 1, wherein the phosphor has a particle size of $d_{90} \leq 20\ \mu m$, $5 \leq d_{50} \leq 10\ \mu m$.

8. (Original) The light emitting device according to claim 1, wherein the light emitting chip emits blue light.

9. (Original) The light emitting device according to claim 1, wherein the phosphor is molded in a periphery of the light emitting chip or on the light emitting chip.

10. (Original) The light emitting device according to claim 1, wherein the phosphor is manufactured by mixing the phosphor with a light transmitting resin.

11. (Original) The light emitting device according to claim 10, wherein the resin is an epoxy resin or a silicon resin.

12. (Original) The light emitting device according to claim 1, wherein the silicate phosphor is a yellow series and the sulfide phosphor is a green series.

13. (Original) A phosphor of a light emitting device, comprising:

a silicate phosphor excited by a light generated by a light emitting chip and having a chemical formula of $Sr_{3-x}SiO_5:Eu^{2+}_x (0 < x \leq 1)$; and

a sulfide phosphor excited by the light generated by the light emitting chip and having a chemical formula of $Sr_{1-x}Ga_2S_4:Eu^{2+}_x(0.001 \leq x \leq 1)$.

14. (Currently Amended) ~~A ligth~~ light emitting device comprising:

a substrate;

a light emitting chip emitting a light;

a connection part for electrically connecting the substrate with the light emitting chip;

a phosphor encapsulating the light emitting chip and through which the light passes;

a silicate phosphor contained in the phosphor and having a chemical formula of $Sr_{3-x}SiO_5:Eu^{2+}_x(0 < x \leq 1)$; and

a sulfide phosphor contained in the phosphor and having a chemical formula of $Sr_{1-x}Ga_2S_4:Eu^{2+}_x(0.001 \leq x \leq 1)$.

15. (Original) The light emitting device according to claim 14, wherein when the light emitting device is a top view type, the silicate phosphor and the sulfide phosphor exist at a ratio of 1 : 2 to 1 : 3.

16. (Original) The light emitting device according to claim 14, wherein when the light emitting device is a side view type, the silicate phosphor and the sulfide phosphor exist at a ratio of 1 : 3 to 1 : 4.

17. (Currently Amended) A ~~ligth~~ light emitting device comprising:

a leadframe;

a light emitting chip emitting a light;

a connection part for electrically connecting the leadframe with the light emitting chip;

a phosphor encapsulating and molding the light emitting chip and through which the light passes;

a silicate phosphor contained in the phosphor and having a chemical formula of $Sr_{3-x}SiO_5:Eu^{2+}_x$ ($0 < x \leq 1$); and

a sulfide phosphor contained in the phosphor and having a chemical formula of $Sr_{1-x}Ga_2S_4:Eu^{2+}_x$ ($0.001 \leq x \leq 1$).

18-21. (Cancelled)